



## T3050H-8E 30A TRIAC

Rev.A.1.0

The T3050H-8E triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. Compared to traditional triacs, T3050H-8E provides a very high switching capability up to junction temperatures of 150°C. Package TO-263 is RoHS compliant.

Symbol	Value	Unit
$I_{T(RMS)}$	30	A

 $V_{DRM}$ 

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-150	
Repetitive peak off-state voltage ( $T_j=25^\circ C$ )	$V_{DRM}$	800	V
Repetitive peak reverse voltage ( $T_j=25^\circ C$ )	$V_{RRM}$	800	V
RMS on-state current ( $T_c = 117^\circ C$ )	$I_{T(RMS)}$	30	A
Non repetitive surge peak on-state current (full cycle , $t_p=20ms$ , $T_j=25^\circ C$ )	$I_{TSM}$	270	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6ms$ , $T_j=25^\circ C$ )		297	
$I^2t$ value for fusing ( $t_p=10ms$ , $T_j=25^\circ C$ )	$I^2t$	365	$A^2s$
Critical rate of rise of on-state current ( $I_G=2I_{GT}$ , $f=100Hz$ , $T_j=150^\circ C$ )	$dI/dt$	100	$A/\mu s$
Peak gate current ( $t_p=20\mu s$ , $T_j=150^\circ C$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=150^\circ C$ )	$P_{G(AV)}$	1	W
Peak gate power	$P_{GM}$	10	W

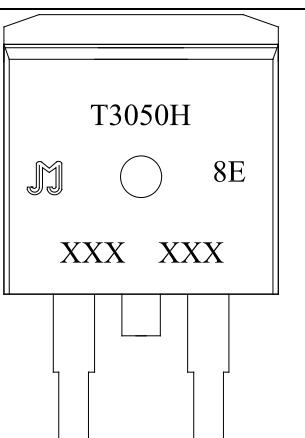
**T3050H-8E**

Peak pulse voltage (T <sub>j</sub> =25 °C; non-repetitive, off-state; FIG.8)	V <sub>PP</sub>	1.2	kV
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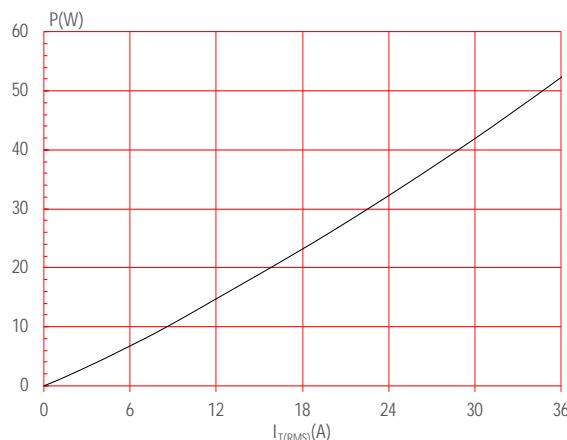
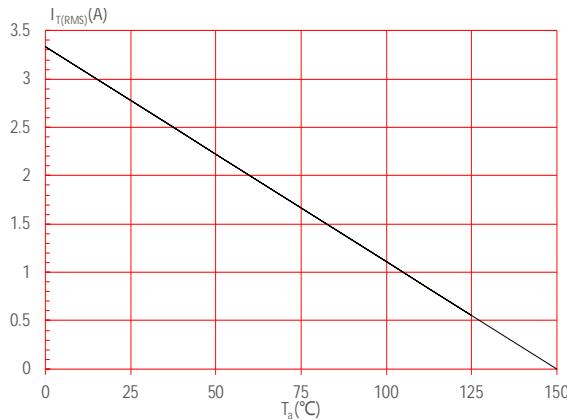
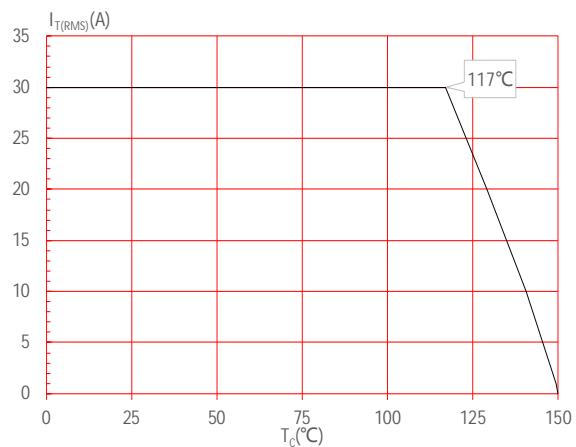
(T<sub>j</sub>=25 °C unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33	- -	MAX.	50	mA
V <sub>GT</sub>		- -	MAX.	1.3	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =150 °C R <sub>L</sub> =3.3K	- -	MIN.	0.15	V

**T 30 50 H -8 E -/**  
Triacs      I<sub>T(RMS)</sub>:30A  
50:I<sub>GT1-3</sub> 50mA      8:V<sub>DRM</sub> /V<sub>RRM</sub> 800V  
High junction temperature  
Blank:Tube  
-TR:Tape & Reel  
E:TO-263



Year      Month      XXX XXX      Production Code

**FIG.1** Maximum power dissipation versus RMS on-state current**FIG.3:** RMS on-state current versus ambient temperature (printed circuit board FR4,copper thickness:35 $\mu$ m)(full cycle)**FIG.2:** RMS on-state current versus case temperature**FIG.4:** Surge peak on-state current versus number of cycles

**FIG.7:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

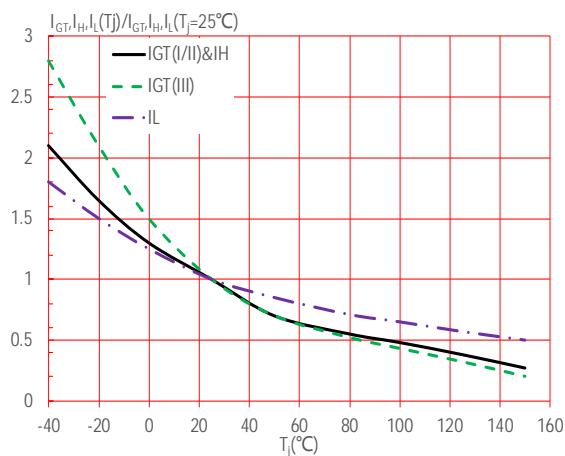
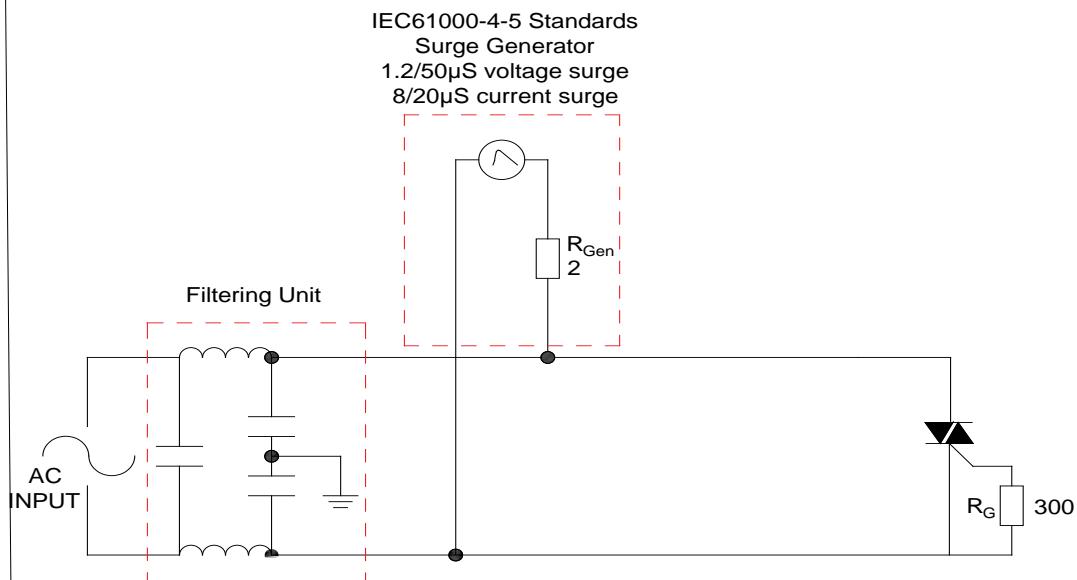
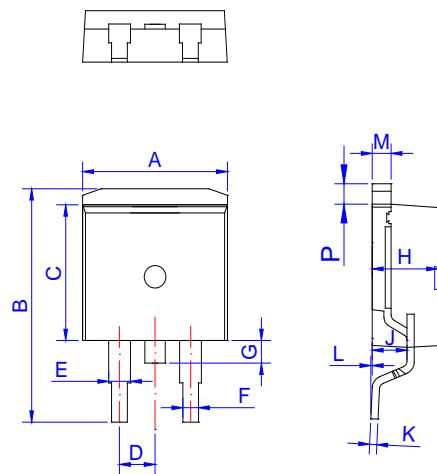


FIG.8 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
T3050H-8E	800	10	TO-263	10	Surface
T3050H-8E-TR	0				



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40		2.70	0.094		0.106
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G	1.00		1.50	0.039		0.059
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0	0.10	0.25	0	0.004	0.010
M	1.25		1.35	0.049		0.053
P	1.20		1.50	0.047		0.059



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